

## [Product Information]

Ver.1.1

# IMX334LQR

Diagonal 8.86 mm (Type 1/1.8) CMOS Solid-state Image Sensor with Square Pixel for Color Cameras

For the latest data sheet, please visit [www.sunnywale.com](http://www.sunnywale.com)

### Description

The IMX334LQR is a diagonal 8.86 mm (Type 1/1.8) CMOS active pixel type solid-state image sensor with a square pixel array and 8.42 M effective pixels. This chip operates with analog 2.9 V, digital 1.2 V, and interface 1.8 V triple power supply, and has low power consumption. High sensitivity, low dark current and no smear are achieved through the adoption of R, G and B primary color mosaic filters. This chip features an electronic shutter with variable charge-integration time.

(Applications: Surveillance cameras, FA cameras, Industrial cameras)

### Features

- ◆ CMOS active pixel type dots
- ◆ Built-in timing adjustment circuit, H/V driver and serial communication circuit
- ◆ Input frequency: 6 to 27 MHz / 37.125 MHz / 74.25 MHz
- ◆ Number of recommended recording pixels: 3840 (H) × 2160 (V) approx. 8.29 M pixels
- ◆ Readout mode
  - All-pixel scan mode
  - Horizontal/Vertical 2/2-line binning mode
  - Window cropping mode
  - Vertical / Horizontal direction-normal / inverted readout mode
- ◆ Readout rate
  - Maximum frame rate in All-pixel scan mode 3840(H) × 2160(V) A/D 12-bit: 60 frame/s
- ◆ High dynamic range (HDR) function
  - Multiple exposure HDR
  - Digital overlap HDR
- ◆ Variable-speed shutter function (resolution 1H units)
- ◆ 10-bit / 12-bit A/D converter
- ◆ CDS / PGA function
  - 0 dB to 72 dB (step pitch 0.3 dB)
  - Supports I/O
  - CSI-2 serial data output ( 4 Lane / 8 Lane, RAW10 / RAW12 output)
- ◆ Recommended exit pupil distance: -30 mm to  $-\infty$

### STARVIS

\* STARVIS is a trademark of Sony Corporation. The STARVIS is back-illuminated pixel technology used in CMOS image sensors for surveillance camera applications. It features a sensitivity of 2000 mV or more per  $1 \mu\text{m}^2$  (color product, when imaging with a 706 cd/m<sup>2</sup> light source, F5.6 in 1 s accumulation equivalent), and realizes high picture quality in the visible-light and near infrared light regions.

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**Device Structure**

- ◆ CMOS image sensor
- ◆ Image size Type 1/1.8
- ◆ Total number of pixels 3952 (H) × 2320 (V) approx. 9.17 M pixels
- ◆ Number of effective pixels 3864 (H) × 2180 (V) approx. 8.42 M pixels
- ◆ Number of active pixels 3864 (H) × 2176 (V) approx. 8.41 M pixels
- ◆ Number of recommended recording pixels 3840 (H) × 2160 (V) approx. 8.29 M pixels
- ◆ Unit cell size 2.0 μm (H) × 2.0 μm (V)
- ◆ Optical black Horizontal (H) direction: Front 0 pixel, rear 0 pixel  
Vertical (V) direction: Front 13 pixels, rear 0 pixel
- ◆ Dummy Horizontal (H) direction: Front 0 pixel, rear 0 pixel  
Vertical (V) direction: Front 0 pixel, rear 0 pixel
- ◆ Package 128 pin LGA

**Image Sensor Characteristics**

(Tj = 60 °C)

Item		Value	Remarks
Sensitivity (F5.6)	Typ.	2200 Digit	1/30 s accumulation 12 bit converted value
Saturation signal	Min.	3895 Digit	12 bit converted value

**Basic Drive Mode**

Drive mode	Recommended number of recording pixels	Maximum frame rate [frame/s]	Output interface	ADC [bit]
All pixel	3840 (H) × 2160 (V) approx. 8.29 M pixels	60	CSI-2	10/12
Horizontal/ Vertical 2/2-line binning	1920 (H) × 1080 (V) approx. 2.07 M pixels	120	CSI-2	10